

January 24, 2013

Product Specifications of the New Low On-State Resistance Power MOSFET Products

Type no.	Drain to source voltage (VDSS) [V]	Gate to source voltage (VGSS) [V]	Drain current (ID) [A]	Drain to source on-state resistance [mΩ]				Input capacitance (Ciss) [pF]	Package
				VGSS = 10 V		VGSS = 4.5 V			
				Typ	Max	Typ	Max		
μPA2766T1A	30	±20	130	0.72	0.88	1.30	1.82	10850	8-pin HVSON
μPA2764T1A	30	±20	130	0.90	1.10	1.60	2.45	7930	
μPA2765T1A	30	±20	100	1.05	1.30	1.85	2.90	6550	